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HEARING AID COMPATIBILITY

Applicant Name:

Samsung Electronics Co., Ltd. 129, Samsung-ro, Maetan dong, Yeongtong-gu, Suwon-si Gyeonggi-do 16677, Korea

Date of Testing: 1/4/2022 - 2/23/2022**Test Site/Location:** PCTEST, Columbia, MD, USA **Test Report Serial No.:** 1M2112270166-15-R3.A3L Date of Issue: 2/23/2022

FCC ID: A3LSMA135U

APPLICANT: SAMSUNG ELECTRONICS CO., LTD.

Scope of Test: RF Emissions Testing

Application Type: Certification FCC Rule Part(s): CFR §20.19(b) **HAC Standard:** ANSI C63.19-2011

285076 D01 HAC Guidance v05

285076 D02 T-Coil testing for CMRS IP v03

DUT Type: Portable Handset

Model: SM-A135U

Additional Model(s): SM-A135U1, SM-A135U1/DS

Test Device Serial No.: Pre-Production Sample [S/N: 10952, 20704]

C63.19-2011 HAC Category: M3 (RF EMISSIONS CATEGORY)

Note: This revised Test Report (S/N: 1M2112270166-15-R3.A3L) supersedes and replaces the previously issued test report on the same subject device for the same type of testing as indicated. Please discard or destroy the previously issued test report(s) and dispose of it accordingly.

This wireless portable device has been shown to be hearing-aid compatible under the above rated category, specified in ANSI/IEEE Std. C63.19-2011 and has been tested in accordance with the specified measurement procedures. Hearing-Aid Compatibility is based on the assumption that all production units will be designed electrically identical to the device tested in this report. Test results reported herein relate only to the item(s) tested. North America bands only.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.

Randy Ortanez President





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1. INTRODUCTION

On July 10, 2003, the Federal Communications Commission (FCC) adopted new rules requiring wireless manufacturers and service providers to provide digital wireless phones that are compatible with hearing aids. The FCC has modified the exemption for wireless phones under the Hearing Aid Compatibility Act of 1998 (HAC Act) in WT Docket 01-309 RM-8658¹ to extend the benefits of wireless telecommunications to individuals with hearing disabilities. These benefits encompass business, social and emergency communications, which increase the value of the wireless network for everyone. An estimated more than 10% of the population in the United States show signs of hearing impairment and of that fraction, almost 80% use hearing aids. Approximately 500 million people worldwide suffer from hearing loss.

Compatibility Tests Involved:

The standard calls for wireless communications devices to be measured for:

- RF Electric-field emissions
- T-coil mode, magnetic-signal strength in the audio band
- T-coil mode, magnetic-signal frequency response through the audio band
- T-coil mode, magnetic-signal and noise articulation index

The hearing aid must be measured for:

- RF immunity in microphone mode
- RF immunity in T-coil mode

In the following tests and results, this report includes the evaluation for a wireless communications device.



Figure 1-1 Hearing Aid in-vitu

¹ FCC Rule & Order, WT Docket 01-309 RM-8658

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2. DUT DESCRIPTION



FCC ID: A3LSMA135U

Manufacturer: Samsung Electronics Co., Ltd.

129, Samsung-ro, Maetan dong,

Yeongtong-gu, Suwon-si Gyeonggi-do 16677, Korea

Model: SM-A135U

Additional Model(s): SM-A135U1, SM-A135U1/DS

Serial Number: 10952, 20704
Antenna Configurations: Internal Antenna
DUT Type: Portable Handset

I. Power Reduction for WIFI

This device uses an independent fixed level power reduction mechanism for 2.4GHz and 5GHz WIFI operations during voice or VoIP held to ear scenarios. Reduced powers were used to evaluate for low-power exemption in Section 9.II for WIFI. Detailed descriptions of the power reduction mechanism are included in the operational description.

II. LTE Band Selection

This device supports LTE capabilities with overlapping transmission frequency ranges. When the supported frequency range of an LTE band falls completely within an LTE band with a larger transmission frequency range, both LTE bands have the same target power (or the band with the larger transmission frequency range has a higher target power), and both LTE bands share the same transmission path and signal characteristics, hearing-aid compatibility compliance was only assessed for the band with the larger transmission frequency range.

III. Device Serial Numbers

Several samples with identical hardware were used to support HAC testing. The manufacturer has confirmed that the device(s) tested have the same physical, mechanical, and thermal characteristics are within operational tolerances expected for production units. The serial numbers used for each test are indicated alongside the results in Section 11.

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Table 2-1 A3LSMA135U HAC Air Interfaces

Air-Interface	Band (MHz)	Type Transport	HAC Tested	Simultaneous But Not Tested	Name of Voice Service
	850	VO	Yes	Yes: WIFI or BT	CMRS Voice
GSM	GSM 1900		163	res. Wiri of Bi	CIVIKS VOICE
	GPRS/EDGE	VD	No ¹	Yes: WIFI or BT	Google Duo
	850				
UMTS	1700	VD	No ¹	Yes: WIFI or BT	CMRS Voice
UIVITS	1900				
	HSPA	VD	No ¹	Yes: WIFI or BT	Google Duo
	680 (B71)		No ^{1 2}		
700 (B12)					
	780 (B13)			Yes: WIFI or BT	VoLTE, Google Duo
	790 (B14)	· VD	No ¹		
	850 (B5)				
LTE (FDD)	850 (B26)				
LIE (FUU)	1700 (B4)				
	1700 (B66)				
	1900 (B2)				
	1900 (B25)				
	2300 (B30)				
	2500 (B7)				
LTE (TDD)	2600 (B38)	VD	Yes	Yes: WIFI or BT	VoLTE, Google Duo
LIE (IDD)	2600 (B41)	VD	162	tes. WIFI OF BT	VOLTE, GOOGIE DUO
	2450				
	5200 (U-NII 1)				
WIFI	5300 (U-NII 2A)	VD	No ¹	Yes: GSM, UMTS, or LTE	VoWIFI, Google Duo
	5500 (U-NII 2C)				
	5800 (U-NII 3)				
ВТ	2450	DT	No	Yes: GSM, UMTS, or LTE	N/A
Type Transport Notes: /O = Voice Only 1. Evaluated for MIF and low-power exemption.					

DT = Digital Data - Not intended for Voice Services VD = CMRS and/or IP Voice over Data Transport

2. LTE B71, while outside the scope of ANSI C63.19 and FCC HAC regulations, was additionally tested according to the existing HAC procedures with currently available test equipment.

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3. ANSI/IEEE C63.19 PERFORMANCE CATEGORIES

I. RF EMISSIONS

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

Category	Telephone RF Parameters			
Near field Category	E-field emissions CW dB(V/m)			
	f < 960 MHz			
M1	50 to 55			
M2	45 to 50			
М3	40 to 45			
M4	< 40			
f > 960 MHz				
M1	40 to 45			
M2	35 to 40			
М3	30 to 35			
M4	< 30			
Table 3-1 WD near-field categories as defined in ANSI C63.19-2011				

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SYSTEM SPECIFICATIONS 4.

EF3DV3 E-Field Probe Description

Construction: One dipole parallel, two dipoles normal to probe axis

Built-in shielding against static charges

Calibration: In air from 30 MHz to 6.0 GHz

(absolute accuracy ±5.1%, k=2)

30 MHz to > 6 GHz; Frequency:

Linearity: ± 0.2 dB (30 MHz to 6 GHz)

± 0.2 dB in air (rotation around probe axis) Directivity

± 0.4 dB in air (rotation normal to probe axis)

2 V/m to > 1000 V/m Dynamic Range

(M3 or better device readings fall well below diode

compression point)

Linearity: ± 0.2 dB

Dimensions Overall length: 337 mm (Tip: 20 mm)

Tip diameter: 4.0 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 1.5 mm



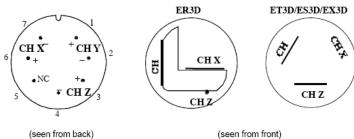
Figure 4-1 E-field Free-space Probe

Probe Tip Description

HAC field measurements take place in the close near field with high gradients. Increasing the measuring distance from the source will generally decrease the measured field values (in case of the validation dipole approx. 10% per mm).

The electric field probes have an irregular internal geometry because it is physically not possible to have the 3 orthogonal sensors situated with the same center. The effect of the different sensor centers is accounted for in the HAC uncertainty budget ("sensor displacement").

Connector Plan



(seen from front)

The antistatic shielding inside the probe is connected to the probe connector case.

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Equation 1

Conversion of Connector Voltage u, to E-Field E,

$$E_i = \sqrt{\frac{u_i + (u_i^2 \cdot CF)/(DCP)}{Norm_i \cdot ConvF}}$$

whereby

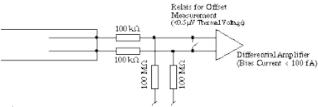
E_i: electric field in V/m

 u_i : voltage of channel i at the connector in μV Norm: sensitivity of channel i in $\mu V/(V/m)^2$ enhancement factor in liquid (ConvF=1 for Air)

DCP: diode compression point in μV

CF: signal crest factor (peak power/average power)

Conditions of Calibration

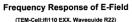


Please note:

- a lower input impedance of the amplifier will result in different sensitivity factors Norm, and DCP
- · larger bias currents will cause higher offset

Probe Response to Frequency

The E-field sensors have inherently a very flat frequency response. They are calibrated with a number of frequencies resulting in a common calibration factor, with the frequency behavior documented in the calibration certificate (See also below).



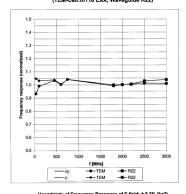


Figure 4-2 E-Field Probe Frequency Response

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SPEAG Robotic System

E-field measurements are performed using the DASY5 automated dosimetric assessment system. The DASY5 is made by Schmid & Partner Engineering AG (SPEAG) in Zurich. Switzerland and consists of high precision robotics system (Staubli), robot controller, Intel CORE i7 computer, near-field probe, probe alignment sensor, and the HAC phantom. The robot is a six-axis industrial robot performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).



Figure 4-3 SPEAG Robotic System

System Hardware

A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and a remote control used to drive the robot motors. The PC consists of the computer with operating system and RF Measurement Software DASY5 v52.8 (with HAC Extension), A/D interface card, monitor, mouse, and keyboard. The Staubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit that performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

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System Electronics

The DAE consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

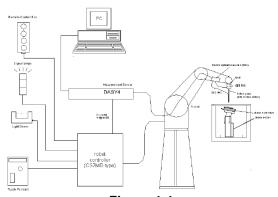


Figure 4-4 SPEAG Robotic System Diagram

DASY5 Instrumentation Chain

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$\begin{aligned} V_i &= U_i + U_i^2 \cdot \frac{cf}{dcp_i} \\ \text{with} \quad V_i &= \text{compensated signal of channel i} & (i = x, y, z) \\ U_i &= \text{input signal of channel i} & (i = x, y, z) \\ cf &= \text{crest factor of exciting field} & (DASY parameter) \\ dcp_i &= \text{diode compression point} & (DASY parameter) \end{aligned}$$

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© 2022 PCTEST **REV 3.5.M** From the compensated input signals the primary field data for each channel can be evaluated:

$$\mathbf{E} - \text{fieldprobes}: \qquad E_i = \sqrt{\frac{V_i}{Norm_i \cdot ConvF}}$$

with V_i = compensated signal of channel i (i = x, y, z) $Norm_i$ = sensor sensitivity of channel i (i = x, y, z)

 $\mu V/(V/m)^2$ for E-field Probes

ConvF = sensitivity enhancement in solution

 E_i = electric field strength of channel i in V/m

The RSS value of the field components gives the total field strength (Hermitian magnitude):

$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

The primary field data are used to calculate the derived field units.

The measurement/integration time per point, as specified by the system manufacturer is >500ms.

The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500ms and a probe response time of <5 ms. In the current implementation, DASY5 waits longer than 100ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.

If the device under test does not emit a CW signal, the integration time applied to measure the electric field at a specific point may introduce additional uncertainties due to the discretization. The tolerances for the different systems had the worst-case of 2.6%.

Environmental Conditions

Environmental conditions such as temperature and relative humidity are monitored to ensure there are no impacts on system specifications. Proper voltage and power line frequency conditions are maintained with three phase power sources. Environmental noise and reflections are monitored through system checks.

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TEST PROCEDURE 5.

I. **RF EMISSIONS**

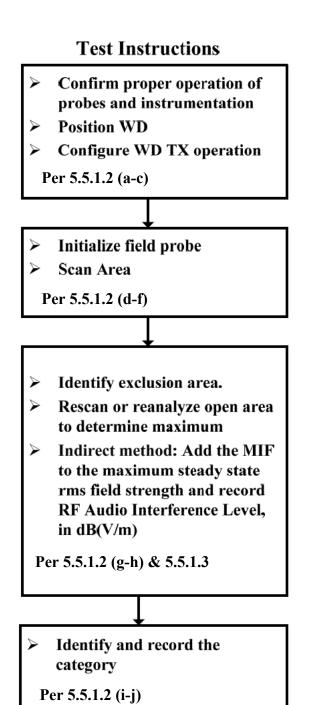


Figure 5-1 RF Emissions Flow Chart

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Test Setup

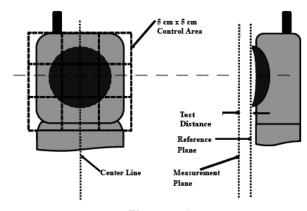


Figure 5-2
E-Field Emissions Test Setup Diagram (See Test Photographs for actual WD scan grid overlay)

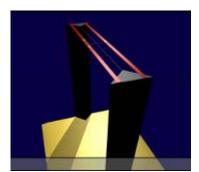


Figure 5-3 HAC Phantom

RF Emissions Test Procedure:

The following illustrate a typical RF emissions test scan over a wireless communications device:

- 1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.
- 2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.
- 3. The WD operation for maximum rated RF output power was configured and confirmed with the base station simulator, at the test channel and other normal operating parameters as intended for the test. The battery was ensured to be fully charged before each test.
- 4. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.
- 5. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC Phantom.
- 6. The measurement system measured the field strength at the reference location.
- 7. Measurements at 2mm or 5mm increments in the 5 x 5 cm region were performed at a distance 15 mm from the center point of the probe measurement element to the WD. Of the 9 subgrids (see Figure 5-2), 3 contiguous subgrids may be excluded from the measurement in order to account for localized areas of higher field intensities. The center subgrid containing the acoustic output or audio band magnetic output may not excluded. A 360° rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.
- 8. The system performed a drift evaluation by measuring the field at the reference location. If the power drift deviated by more than 5%, the HAC test and drift measurements were repeated.

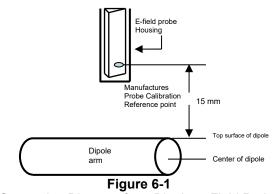
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6. SYSTEM CHECK

I. System Check Parameters

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power P = 100mW RMS (20dBm RMS) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 15 mm probe to dipole separation, which is measured from top surface of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is shown in the following diagram:



Separation Distance from Dipole to Field Probe

RF power was recorded using both an average reading meter and a peak reading meter. Readings of the probe are provided by the measurement system.

To assure proper operation of the near-field measurement probe the input power to the dipole shall be commensurate with the full rated output power of the wireless device [e.g. - for a cellular phone wireless device the average peak antenna input power will be on the order of 100mW (20dBm) RMS] after adjustment for any mismatch.

II. Validation Procedure

A dipole antenna meeting the requirements given in C63.19 was placed in the position normally occupied by the WD.

The length of the dipole was scanned, and the average peak value was recorded.

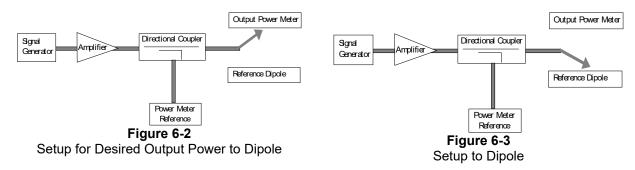
Measurement of CW

Using the near-field measurement system, scan the antenna over the radiating dipole and record the greatest field reading observed. Due to the nature of E-fields about free-space dipoles, the two E-field peaks measured over the dipole are averaged to compensate for non-parallelity of the setup (see manufacturer method on dipole calibration certificates, page 2). Field strength measurements shall be made only when the probe is stationary.

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RF power was recorded using both an average and a peak power reading meter.

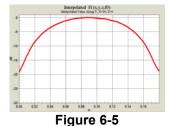


Using this setup configuration, the signal generator was adjusted for the desired output power (100mW) at a specified frequency. The reference power from the coupled port of the directional coupler is recorded. Next, the output cable is connected to the reference dipole, as shown in Figure 6-3.

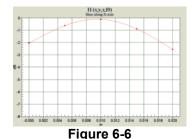
The input signal level was adjusted until the reference power from the coupled port of the directional coupler was the same as previously recorded, to compensate for the impedance mismatch between the output cable and the reference dipole. To assure proper operation of the near-field measurement probe the input power to the reference dipole was verified to the full rated output power of the wireless device. The dipole was secured in a holder in a manner to meet the 20 dB reflection. The near-field measurement probe was positioned over the dipole. The antenna was scanned over the appropriate sized area to cover the dipole from end to end. SPEAG uses 2D interpolation algorithms between the measured points. Please see below two dimensional plots showing that the interpolated values interpolate smoothly between 5mm steps for a free-space RF dipole:



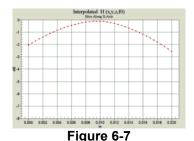
2-D Raw Data from scan along dipole axis



2-D Interpolated points from scan along dipole axis



2-D Raw Data from scan along transverse axis



2-D Interpolated points from scan along transverse axis

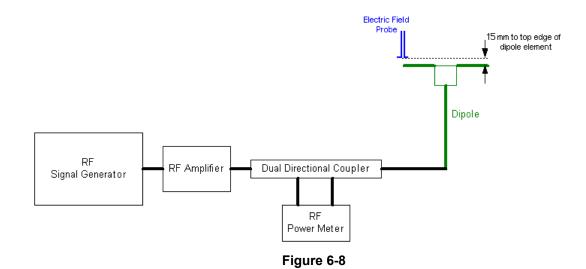
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III. System Check Results

Table 6-1RFE System Verification Results

Date	Frequency (MHz)	Probe S/N	DAE S/N	Dipole S/N	Input Power (dBm)	E-field Result (V/m)	Target Field (V/m)	% Deviation
2/21/2022	835			1003	20.0	112.7	108.4	4.0%
2/21/2022	1880	4035	1533	1137	20.0	92.1	87.9	4.8%
1/4/2021	2600			1012	20.0	88.4	86.5	2.2%



System Check Setup

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7. MODULATION INTERFERENCE FACTOR

I. Measuring Modulation Interference Factors

For any specific fixed and repeatable modulated signal, a modulation interference factor (MIF, expressed in dB) may be determined that relates its interference potential to its steady-state RMS signal level or average power level. This factor is a function only of the audio-frequency amplitude modulation characteristics of the signal and is the same for field-strength and conducted power measurements. The MIF is valid only for a specific repeatable audio-frequency amplitude modulation characteristic; any change in modulation characteristic requires determination and application of a new MIF.

The MIF may be determined using a radiated RF field or a conducted RF signal:

- a. Using RF illumination or conducted coupling, apply the specific modulated signal in question to the measurement system at a level within its confirmed operating dynamic range.
- b. Measure the steady-state RMS level at the output of the fast probe or sensor.
- c. Measure the steady-state average level at the weighting output.
- d. Without changing the square-law detector or weighting system, and using RF illumination or conducted coupling, substitute for the specific modulated signal a 1 kHz, 80% amplitude modulated carrier at the same frequency and adjust its strength until the level at the weighting output equals the step c) measurement.
- e. Without changing the carrier level from step d), remove the 1 kHz modulation and again measure the steady-state RMS level indicated at the output of the fast probe or sensor.
- f. The MIF for the specific modulation characteristic is provided by the ratio of the step e) measurement to the step b) measurement, expressed in dB (20 × log[(step e)/(step b)]).

The following procedure was used to measure the MIF using the SPEAG Audio Interference Analyzer (AIA), Type No: SE UMS 170 CB, Serial No.: 1010:

- 1. The device was placed into a simulated call using a base station simulator or set to transmit using test software for a given mode.
- 2. The device was then set to continuously transmit at maximum power.
- 3. Using a coupler if needed, the device output signal was connected to the RF In port of the AIA, which was connected to a desktop computer. Alternatively, a radiated RF signal may be used with the AIA's built-in antenna.
- 4. The MIF measurement procedure in the DASY software was run, and the resulting MIF value was recorded.
- 5. Steps 1-4 were repeated for all CMRS air interfaces, frequency bands, and modulations.

The modulation interference factors obtained were applied to readings taken of the actual wireless device in order to obtain an accurate audio interference level reading using the formula:

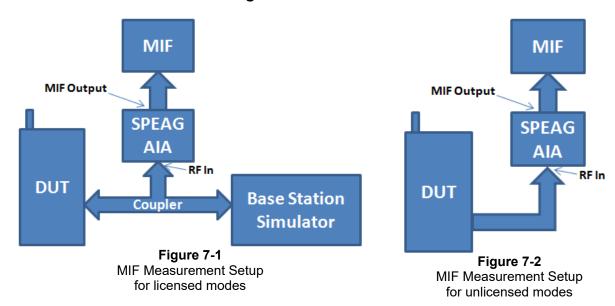
Audio Interference Level [dB(V/m)] = 20 * log[Raw Field Value (V/m)] + MIF (dB)

Because the MIF value is output power independent, MIF values for a given mode should be constant across all devices; however, per C63.19-2011 §D.7, MIF values should be measured for each device being evaluated. The applicable modes for this device have been investigated in this section of the report.

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II. MIF Measurement Block Diagrams



III. Measured Modulation Interference Factors:

Table 7-1GSM Modulation Interference Factors¹

CON MODULATION INTERFERENCE T ACTORS							
Mode			GSM850		GSM1900		
IVIC	Jue	128	190	251	512 661 810		
CCM	Voice	3.55	3.54	3.55	3.54	3.54	3.54
GSM	EDGE	4.18	4.22	4.21	4.00	4.35	4.74

Table 7-2UMTS Modulation Interference Factors¹

	OWITS Modulation interference Factors									
Mode		UMTS V			UMTS IV			UMTS II		
		4132	4183	4233	1312	1412	1513	9262	9400	9538
	12.2 kbps RMC	-20.84	-21.50	-20.56	-22.63	-20.39	-21.36	-21.00	-21.51	-21.48
UMTS	12.2 kbps AMR	-12.93	-12.33	-12.44	-12.44	-12.87	-12.82	-12.00	-12.02	-11.65
	HSUPA Subtest1	-20.26	-20.06	-18.15	-18.93	-17.99	-18.48	-19.48	-19.43	-19.64

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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Table 7-3 LTE FDD Modulation Interference Factors^{1,2}

			IIIGHEIGH	oc i doloio			
LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
71	680.5	133297	20	16QAM	1	0	-10.63
12	707.5	23095	10	16QAM	1	0	-10.33
13	782.0	23230	10	16QAM	1	0	-10.47
14	793.0	23330	10	16QAM	1	0	-10.56
26	831.5	26865	15	16QAM	1	0	-10.46
66	1745.0	132322	20	16QAM	1	0	-10.04
25	1882.5	26365	20	16QAM	1	0	-10.27
30	2310.0	27710	10	16QAM	1	0	-10.44
7	2535.0	21100	20	16QAM	1	0	-10.15
66	1745.0	132322	20	QPSK	1	0	-14.90
66	1745.0	132322	20	64QAM	1	0	-9.56
66	1745.0	132322	20	64QAM	1	50	-9.48
66	1745.0	132322	20	64QAM	1	99	-9.41
66	1745.0	132322	20	64QAM	50	0	-15.91
66	1745.0	132322	20	64QAM	100	0	-17.47
66	1745.0	132322	15	64QAM	1	74	-9.94
66	1745.0	132322	10	64QAM	1	49	-9.44
66	1745.0	132322	5	64QAM	1	24	-9.52
66	1745.0	132322	3	64QAM	1	14	-9.82
66	1745.0	132322	1.4	64QAM	1	5	-9.48
66	1720.0	132072	20	64QAM	1	99	-9.30
66	1770.0	132572	20	64QAM	1	99	-9.68

Table 7-4 LTE TDD B41 Power Class 3 Modulation Interference Factors^{1,3}

LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
41	2593.0	40620	20	QPSK	1	0	1.42
41	2593.0	40620	20	16QAM	1	0	1.53
41	2593.0	40620	20	64QAM	1	0	1.34
41	2593.0	40620	20	16QAM	1	50	1.53
41	2593.0	40620	20	16QAM	1	99	1.53
41	2593.0	40620	20	16QAM	50	0	1.34
41	2593.0	40620	20	16QAM	100	0	1.35
41	2593.0	40620	15	16QAM	1	0	1.60
41	2593.0	40620	10	16QAM	1	0	1.52
41	2593.0	40620	5	16QAM	1	0	1.45
41	2506.0	39750	15	16QAM	1	0	1.49
41	2549.5	40185	15	16QAM	1	0	1.50
41	2636.5	41055	15	16QAM	1	0	1.44
41	2680.0	41490	15	16QAM	1	0	1.44

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

³ Note: LTE TDD Power Class 3 MIFs were taken using UL-DL Configuration 2. More information about the chosen UL-DL Configuration can be found in Section 10.

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² Note: All FDD LTE bands were found to have substantially similar MIF values given similar RB, BW, and modulation configurations.

Table 7-5LTE TDD B41 Power Class 2 Modulation Interference Factors^{1,2}

				oddialion			
LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
41	2593.0	40620	20	QPSK	1	0	-1.65
41	2593.0	40620	20	16QAM	1	0	-1.58
41	2593.0	40620	20	64QAM	1	0	-1.51
41	2593.0	40620	20	64QAM	1	50	-1.51
41	2593.0	40620	20	64QAM	1	99	-1.51
41	2593.0	40620	20	64QAM	50	0	-1.71
41	2593.0	40620	20	64QAM	100	0	-1.69
41	2593.0	40620	15	64QAM	1	0	-1.44
41	2593.0	40620	10	64QAM	1	0	-1.49
41	2593.0	40620	5	64QAM	1	0	-1.67
41	2506.0	39750	15	64QAM	1	0	-1.59
41	2549.5	40185	15	64QAM	1	0	-1.51
41	2636.5	41055	15	64QAM	1	0	-1.49
41	2680.0	41490	15	64QAM	1	0	-1.61

Table 7-6

802.11b (2.4GHz, SISO) Modulation Interference Factors^{1,3}

	802.1	1b MIF Mea	surement	s [dB]		
Mode		Data Rat	e [Mbps]			
	1 2 5.5 11					
802.11b	-9.41	-8.72	-7.00	-5.79		

Table 7-7

802.11g (2.4GHz, SISO) Modulation Interference Factors^{1,3}

			802.1°	1g MIF Mea	surement	s [dB]		
Mode		Data Rate [Mbps]						
	6 9 12 18 24 36 48							54
802.11g	-7.10	-6.33	-5.58	-5.02	-4.52	-3.96	-4.12	-4.37

Table 7-8

802.11n (2.4GHz, SISO) Modulation Interference Factors^{1,3}

	002.1111	<u> </u>	, cicc, i	vioudiati	on micon	0101100 1	actore		
	802.11n (2.4GHz) MIF Measurements [dB]								
Mode		MCS Index							
	0	0 1 2 3 4 5 6 7							
802.11n	-7.03	-5.71	-5.02	-4.60	-4.03	-4.11	-4.33	-4.30	

Table 7-9

802.11a (5GHz, 20MHz BW, SISO) Modulation Interference Factors^{1,3}

		802.11a MIF Measurements [dB]								
Mode		Data Rate [Mbps]								
	6 9 12 18 24 36 48 5									
802.11a	-11.57	-10.96	-9.94	-9.91	-9.19	-9.09	-9.54	-10.47		

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

³ Note: WIFI MIF values were found to be independent of the transmit channel.

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² Note: LTE TDD Power Class 2 MIFs were taken using UL-DL Configuration 1. More information about the chosen UL-DL Configuration can be found in Section 10.

Table 7-10

802.11n (5GHz, 20MHz BW, SISO) Modulation Interference Factors^{1,2}

	20MHz BW 802.11n (5GHz) MIF Measurements [dB]									
Mode		MCS Index								
	0	0 1 2 3 4 5 6 7								
802.11n	-11.61	-10.38	-9.86	-9.70	-9.71	-9.53	-10.41	-10.02		

Table 7-11

802.11ac (5GHz, 20MHz BW, SISO) Modulation Interference Factors^{1,2}

		•	20MH	z BW 802.	11ac (5GH	z) MIF Mea	surement	s [dB]		
Mode		MCS Index								
	0	1	2	3	4	5	6	7	8	9
802.11ac	-11.80	-10.53	-9.87	-9.67	-9.72	-9.53	-10.31	-9.83	-10.76	N/A

Table 7-12

802.11n (5GHz, 40MHz BW, SISO) Modulation Interference Factors^{1,2}

002.1	111 (0011	2, 1011111	<u> </u>	100) Wio	adidion	1111011010	1100 1 40	.010			
		40MHz BW 802.11n (5GHz) MIF Measurements [dB]									
Mode		MCS Index									
	0	0 1 2 3 4 5 6 7									
802.11n	-9.61	-10.40	-8.63	-8.99	-8.97	-8.05	-9.16	-8.21			

Table 7-13

802.11ac (5GHz, 40MHz BW, SISO) Modulation Interference Factors^{1,2}

			40MH	z BW 802.	11ac (5GH	z) MIF Mea	surement	s [dB]		
Mode		MCS Index								
	0 1 2 3 4 5 6							7	8	9
802.11ac	-9.67	-8.15	-7.55	-8.70	-10.24	-9.23	-8.41	-8.32	N/A	-8.78

Table 7-14

802.11ac (5GHz, 80MHz BW, SISO) Modulation Interference Factors^{1,2}

80MHz BW 802.11ac (5GHz) MIF Measurements [dB]						s [dB]				
Mode	MCS Index									
	0	1	2	3	4	5	6	7	8	9
802.11ac	-7.20	-7.11	-7.57	-7.52	-7.49	-7.46	-6.94	-7.73	-7.55	-7.59

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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² Note: WIFI MIF values were found to be independent of the transmit channel.

8. CONDUCTED POWER CONFIGURATIONS AND TARGETS

I. **Procedures Used to Establish RF Signal for HAC Testing**

The handset was configured to transmit the required air interface in a shielded chamber. Measurements were taken with a fully charged battery.

II. **HAC Target Powers**

All applicable modes supported by the device have their held-to-ear conducted power targets listed below and were used for the individual mode evaluations in Section 9. All conducted power targets have a tolerance of +1.0dB and -1.5dB unless otherwise noted. For WIFI modes, the overall maximum power amongst all bands per IEEE standards is listed with no lower tolerance.

III. **RF Conducted Power Measurement Setup and Conditions**

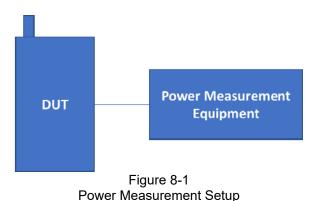
Output Power Verification

Maximum output power is verified for all applicable test channels for all air interfaces which require test scans. See Table 8-1 for air interface specific settings of transmit power parameters. See Table 9-1 for more information regarding which modes required test scans and had conducted power measurements taken.

> Table 8-1 Power Control Parameters and Settings by Air Interface

	Air Interface:	Parameter Name:	Parameter Set To:
	GSM	PCL	GSM850: "5"; GSM1900: "0"
	UMTS	TPC	"All 1's"
	LTE	TPC	"Max Power"
Ī	WIFI	PLS	Mfr Specified

The general setup for conducted powers included in Section 11 is shown in Figure 8-1 below. The power measurement equipment could be a base station simulator, signal analyzer, or power meter depending on the applicable air interface.



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IV. GSM Target Powers

Table 8-2
GSM Conducted Power Targets

Com Comadeted Fower Targets					
Band	Modulated Average C	Output Power (in dBm)			
band	Voice	Data			
GSM/EDGE 850	32.5	26.5			
GSM/EDGE 1900	30.0	25.0			

V. UMTS Target Powers

Table 8-3
UMTS Conducted Power Targets

Omito conducted rower rangets					
Band	Modulated Average Output Power (in dBm)				
band	3GPP WCDMA Rel 99	3GPP HSUPA Rel 6			
UMTS V	24.0	23.0			
UMTS IV	24.0	23.0			
UMTS II	24.0	23.0			

VI. LTE FDD Target Powers

Table 8-4
LTE FDD Conducted Power Targets

Band	Modulated Average Output Power (in dBm)
LTE Band 71	24.0
LTE Band 12	24.5
LTE Band 13	24.5
LTE Band 14	24.0
LTE Band 5	24.0
LTE Band 26	24.0
LTE Band 4	24.0
LTE Band 66	24.0
LTE Band 2	24.0
LTE Band 25	24.0
LTE Band 30	21.5
LTE Band 7	23.0

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VII. LTE TDD Target Powers

Table 8-5
LTE TDD Conducted Power Targets

LIL IDD Colladoto	a i owei iaigets
Band	Modulated Average Output Power (in dBm)
LTE Band 38	23.0
LTE Band 41 PC3	23.0
LTE Band 41 PC2	26.0

VIII. WIFI Target Powers

Table 8-6
IEEE 802_11a/b/g/n/ac Reduced Average RF Power Targets¹

Band	Modulated Average Output Power (in dBm)
WLAN - 2.4GHz	12.0
WLAN - 5GHz	10.0

¹ Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in 2.4GHz and 5GHz WIFI modes for held-to-ear scenarios.

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JUSTIFICATION OF HELD TO EAR MODES TESTED 9.

I. **Analysis of RF Air Interface Technologies**

An analysis was performed, following the guidance of §4.3 and §4.4 of the ANSI standard, of the RF air interface technologies being evaluated. The factors that will affect the RF interference potential were evaluated, and the worst-case operating modes were identified and used in the evaluation. A WD's interference potential is a function both of the WD's average near-field field strength and of the signal's audio-frequency amplitude modulation characteristics. Per §4.4, RF air interface technologies that have low power have been found to produce sufficiently low RF interference potential, so it is possible to exempt them from the product testing specified in Clause 5 of the ANSI standard. An RF air interface technology of a device is exempt from testing when its average antenna input power plus its MIF is ≤17dBm for all of its operating modes. RF air interface technologies exempted from testing in this manner are automatically assigned an M4 rating to be used in determining the overall rating for the WD.

The worst-case MIF plus the worst-case average antenna input power for all modes are investigated below to determine the testing requirements for this device.

II. Individual Mode Evaluations

Table 9-1 Max Power + MIF calculations for Low Power Exemptions

Air Interface	Maximum Average Power (dBm)	Worst Case MIF (dB)	Total (Power + MIF, dB)	C63.19 Testing Required
GSM - GSM850	24.31*	3.55	27.86	Yes
GSM - GSM1900	21.81*	3.54	25.35	Yes
GSM - EDGE850	18.31*	4.22	22.53	Yes**
GSM - EDGE1900	16.81*	4.74	21.55	Yes**
UMTS - RMC	25.00	-20.39	4.61	No
UMTS - AMR	25.00	-11.65	13.35	No
UMTS - HSPA	24.00	-17.99	6.01	No
LTE FDD	25.50	-9.30	16.20	No
LTE TDD - Band 41 (PC3)	17.31*	1.60	18.91	Yes
LTE TDD - Band 41 (PC2)	23.16*	-1.44	21.72	Yes
WIFI - 2.4GHz	13.00	-3.96	9.04	No
WIFI - 5GHz	11.00	-6.94	4.06	No

^{*} Note: ANSI C63.19-2011 Sec. 4.4 Footnote 20 indicates the use of a long averaging time for measuring the antenna input power when using this method of exclusion. Therefore, the frame averaged power was calculated for these modes in this investigation.

III. **Low-Power Exemption Conclusions**

Per ANSI C63.19-2011. RF Emissions testing for this device is required only for GSM voice mode as well as LTE TDD (Power Class 3 and Power Class 2) data mode. All other air interfaces are exempt.

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^{**} Note: EDGE data modes were considered but not tested as GSM voice modes were found to be the worst-case modes for the GSM air interface.

10. LTE TDD UPLINK-DOWNLINK CONFIGURATION

I. Uplink-Downlink Configuration Additional Testing

Additional testing was performed on each supported power class for LTE TDD to determine the worst-case Uplink-Downlink configuration for RFE testing.

Per 3GPP TS 36.211, the total frame length for each TDD radio frame of length T_f = 307200 · T_s = 10 ms, where T_s is a number of time units equal to 1/(15000 x 2048) seconds. Additionally, each radio frame consists of 10 subframes, each of length $30720 \cdot T_s$ = 1 ms, and subframes can be designated as uplink (U), downlink (D), or special subframe (S), depending on the Uplink-Downlink configuration as indicated in Table 4.2-2 of 3GPP TS 36.211. In the transmission duty factor calculation, the special subframe configuration with the shortest UpPTS duration within the special subframe is used and will be applied for measurement. From 3GPP TS 36.211 Table 4.2-1, the shortest UpPTS is 2192 · Ts which occurs in the normal cyclic prefix and special subframe configuration 4.

See table below outlining the calculated transmission duty cycles for each Uplink-Downlink configuration:

Table 10-1Uplink-Downlink Configurations for Type 2 Frame Structures

Uplink-downlink configuration	Downlink-to-Uplink Switch-point periodicity				Calculated Transmission							
configuration	Switch-point periodicity	0	1	2	3	4	5	6	7	8	9	Duty Cycle (%)
0	5 ms	D	S	٦	٦	U	D	S	٦	U	٥	61.4%
1	5 ms	D	S	J	J	D	D	S	J	U	D	41.4%
2	5 ms	D	S	כ	D	D	D	S	כ	D	D	21.4%
3	10 ms	D	S	٦	٦	U	D	D	D	D	D	30.7%
4	10 ms	D	S	٦	٦	D	D	D	D	D	D	20.7%
5	10 ms	D	S	U	D	D	D	D	D	D	D	10.7%
6	5 ms	D	S	U	U	U	D	S	U	U	D	51.4%

II. Power Class 3 Uplink-Downlink Configuration Additional Testing

LTE TDD was evaluated with the following radio configuration: channel 40620, 20MHz BW, QPSK, 1RB, 0RB Offset. For Power Class 3, all configurations (0-6) are supported. The configuration which resulted in the worst-case emission was used for full testing. See Table 10-2 below for results. The configuration determined in the results below was used to measure the MIF values in Table 7-4.

Table 10-2LTE TDD Power Class 3 UL-DL Configuration Results

							J. J.S.				0111100				
Mode / Band	Bandwidth (MHz)	Channel	UL-DL Config.		RB Size	RB Offset	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons														
	20	40620	0	QPSK	1	0	Acoustic	14.28	23.09	-3.54	19.55	35.00	-15.45	M4	1,2,3
	20	40620	1	QPSK	1	0	Acoustic	11.82	21.45	-1.64	19.81	35.00	-15.19	M4	1,2,3
	20	40620	2	QPSK	1	0	Acoustic	8.50	18.59	1.43	20.02	35.00	-14.98	M4	1,2,3
LTE TDD / Band 41	20	40620	3	QPSK	1	0	Acoustic	10.41	20.35	-1.58	18.77	35.00	-16.23	M4	1,2,3
	20	40620	4	QPSK	1	0	Acoustic	8.43	18.52	0.53	19.05	35.00	-15.95	M4	1,2,3
	20	40620	5	QPSK	1	0	Acoustic	6.48	16.23	3.57	19.80	35.00	-15.20	M4	1,2,3
	20	40620	6	QPSK	1	0	Acoustic	12.99	22.27	-2.57	19.70	35.00	-15.30	M4	1,2,3

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III. Power Class 2 Uplink-Downlink Configuration Additional Testing

LTE TDD was evaluated with the following radio configuration: channel 40620, 20MHz BW, QPSK, 1RB, 0RB Offset. For Power Class 2, only configurations 1-5 are supported. The configuration which resulted in the worst-case emission was used for full testing. See Table 10-3 below for results. The configuration determined in the results below was used to measure the MIF values in Table 7-5.

Table 10-3LTE TDD Power Class 2 UL-DL Configuration Results

Mode / Band	Bandwidth (MHz)	Channel	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons														
	20	40620	1	QPSK	1	0	Acoustic	21.89	26.80	-1.65	25.15	35.00	-9.85	M4	1,2,3
	20	40620	2	QPSK	1	0	Acoustic	14.39	23.16	1.43	24.59	35.00	-10.41	M4	1,2,3
LTE TDD / Band 41	20	40620	3	QPSK	1	0	Acoustic	18.58	25.38	-1.53	23.85	35.00	-11.15	M4	1,2,3
	20	40620	4	QPSK	1	0	Acoustic	15.28	23.68	0.58	24.26	35.00	-10.74	M4	1,2,3
	20	40620	5	QPSK	1	0	Acoustic	10.25	20.21	3.63	23.84	35.00	-11.16	M4	1,2,3

IV. Conclusion

Per the results above, UL-DL Configuration 2 was used for LTE TDD Power Class 3 and UL-DL Configuration 1 was used for LTE TDD Power Class 2 testing.

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11. OVERALL MEASUREMENT SUMMARY

FCC ID:	A3LSMA135U
S/N:	10952, 20704

I. E-FIELD EMISSIONS:

Table 11-1 HAC Data Summary for GSM E-field

Mode	Channel	DUT SN	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons											
	128	20704	Acoustic	33.01	43.75	32.82	3.55	36.37	45.00	-8.63	M4	1,2,4
GSM850	190	20704	Acoustic	33.23	40.22	32.09	3.54	35.63	45.00	-9.37	M4	1,2,4
	251	20704	Acoustic	33.49	35.86	31.09	3.55	34.64	45.00	-10.36	M4	1,2,4
	512	20704	Acoustic	30.47	16.80	24.51	3.54	28.05	35.00	-6.95	M4	7,8,9
CCM4000	661	20704	Acoustic	30.26	18.53	25.36	3.54	28.90	35.00	-6.10	M4	7,8,9
GSM1900	810	20704	Acoustic	30.17	21.23	26.54	3.54	30.08	35.00	-4.92	М3	7,8,9
	910	20704	T Coil	20.17	10.05	25.06	2.54	20.50	25.00	E E0	Ma	400

Table 11-2
HAC Data Summary for LTE TDD Band 41 (Power Class 3) E-field

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Mode / Band	Bandwidth (MHz)	Channel	DUT SN	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons																
	15	39750	10952	2	QPSK	1	0	Acoustic	23.55	10.44	20.37	1.49	21.86	35.00	-13.14	M4	1,2,3
	15	40185	10952	2	QPSK	1	0	Acoustic	23.59	11.05	20.87	1.50	22.37	35.00	-12.63	M4	1,2,3
LTE TDD / Band 41 PC3	15	40620	10952	2	QPSK	1	0	Acoustic	23.37	8.25	18.33	1.60	19.93	35.00	-15.07	M4	1,2,3
	15	41055	10952	2	QPSK	1	0	Acoustic	23.08	7.33	17.30	1.44	18.74	35.00	-16.26	M4	1,2,3
	15	41490	10952	2	QPSK	1	0	Acoustic	23.05	7.49	17.49	1.44	18.93	35.00	-16.07	M4	1,2,3

Table 11-3
HAC Data Summary for LTE TDD Band 41 (Power Class 2) E-field

Mode / Band	Bandwidth (MHz)	Channel	DUT SN	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons																
	15	39750	10952	1	QPSK	1	0	Acoustic	25.91	19.98	26.01	-1.59	24.42	35.00	-10.58	M4	1,2,3
	15	40185	10952	1	QPSK	1	0	Acoustic	26.05	23.10	27.27	-1.51	25.76	35.00	-9.24	M4	1,2,3
LTE TDD / Band 41 PC2	15	40620	10952	1	QPSK	1	0	Acoustic	25.87	22.22	26.93	-1.44	25.49	35.00	-9.51	M4	1,2,3
	15	41055	10952	1	QPSK	1	0	Acoustic	25.69	22.06	26.87	-1.49	25.38	35.00	-9.62	M4	1,2,3
	15	41490	10952	1	QPSK	1	0	Acoustic	25.45	19.62	25.85	-1.61	24.24	35.00	-10.76	M4	1,2,3

II. Worst-case Configuration Evaluation

Table 11-4
Peak Reading 360° Probe Rotation at Azimuth axis

Mode	Channel	DUT SN	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
Probe Rotation	at Worst-Case)									
GSM1900	810	20704	Acoustic	21.38	26.60	3.54	30.14	35.00	-4.86	М3	7,8,9

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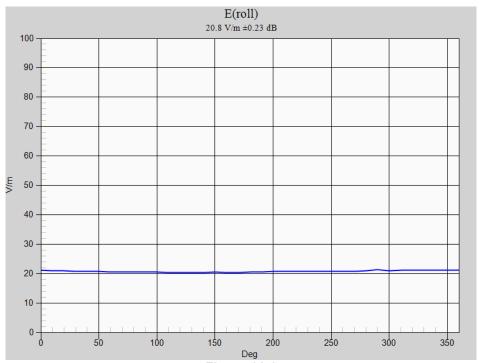


Figure 11-1
Worst-Case Probe Rotation about Azimuth axis

* Note: Locations of probe rotation (with and without exclusions) are shown in Figure 11-2 denoted by the green square markers.



Figure 11-2
Sample E-field Scan Overlay
(See Test Setup Photographs for actual WD overlay.)

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EQUIPMENT LIST 12.

Table 12-1 Equipment List

		Equipment Elec				
Manufacturer	Model	Description	Cal Date	Cal Interval	Cal Due	Serial Number
Agilent	E4438C	ESG Vector Signal Generator	9/28/2021	Annual	9/28/2022	MY45091346
Agilent	N5182A	MXG Vector Signal Generator	7/6/2021	Annual	7/6/2022	MY48180366
(eysight Technologie	N9020A	MXA Signal Analyzer	2/24/2021	Annual	2/24/2022	MY48010233
Amplifier Research	15S1G6	Amplifier	N/A	CBT*	N/A	433978
Anritsu	MA2411B	Pulse Power Sensor	3/8/2021	Annual	3/8/2022	1339007
Anritsu	MA2411B	Pulse Power Sensor	3/9/2021	Annual	3/9/2022	1207470
Anritsu	MA24106A	USB Power Sensor	8/10/2021	Annual	8/10/2022	1231538
Anritsu	MA24106A	USB Power Sensor	8/10/2021	Annual	8/10/2022	1231535
Anritsu	ML2496A	Power Meter	2/19/2021	Annual	2/19/2022	1138001
Control Company	4040	Therm./ Clock/ Humidity Monitor	3/6/2020	Biennial	3/6/2022	200170289
Mini-Circuits	NLP-1200+	Low Pass Filter DC to 1000 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	NLP-2950+	Low Pass Filter DC to 2700 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	BW-N20W5	Power Attenuator	N/A	CBT*	N/A	1226
Pasternack	PE2237-20	Bidirectional Coupler	N/A	CBT*	N/A	N/A
Rohde & Schwarz	CMW500	Wideband Radio Communication Tester	2/10/2021	Annual	2/10/2022	161662
Rohde & Schwarz	CMW500	Wideband Radio Communication Tester	3/22/2021	Annual	3/22/2022	162125
Rohde & Schwarz	CMW500	Radio Communication Tester	9/30/2021	Annual	9/30/2022	140144
Rohde & Schwarz	CMW500	Radio Communication Tester	7/19/2021	Annual	7/19/2022	128635
Seekonk	NC-100	Torque Wrench (8" lb)	8/4/2020	Biennial	8/4/2022	N/A
SPEAG	AIA	Audio Interference Analzyer	N/A	CBT*	N/A	1010
SPEAG	EF3DV3	Freespace E-field Probe	2/15/2021	Biennial	2/15/2023	4035
SPEAG	CD835V3	Freespace 835 MHz Dipole	1/14/2021	Biennial	1/14/2023	1003
SPEAG	CD1880V3	Freespace 1880 MHz Dipole	1/14/2021	Biennial	1/14/2023	1137
SPEAG	CD2600V3	Freespace 2600MHz Dipole	1/14/2021	Biennial	1/14/2023	1012
SPEAG	DAE4	Dasy Data Acquisition Electronics	12/8/2021	Annual	12/8/2022	1533

Calibration traceable to the National Institute of Standards and Technology (NIST).

*Note: CBT (Calibrated Before Testing). Prior to testing, the measurement paths containing a cable, attenuator, coupler or filter were connected to a calibrated source (i.e. a signal generator) to determine the losses of the measurement path. The power meter offset was then adjusted to compensate for the measurement system losses. This level offset is stored within the power meter before measurements are made. This calibration verification procedure applies to the system verification and output power measurements. The calibrated reading is then taken directly from the power meter after compensation of the losses for all final power measurements.

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13. MEASUREMENT UNCERTAINTY

Table 13-1 Uncertainty Estimation Table

Uncertainty Estimation Table Wireless Communications Device Near-Field Measurement							
		Uncert	ainty Estima	ation			
Uncertainty Component	Data (dB)	Data Type	Prob. Dist.	Divisor	Ci (E)	Unc. (dB)	Notes/Comments
Measurement System						-	
RF System Reflections	0.50	Tolerance	N	1.00	1	0.50	* Refl. < -20 dB
Field Probe Calibration	0.21	Tolerance	N	1.00	1	0.21	
Field Probe Isotropy	0.01	Tolerance	N	1.00	1	0.01	
Field Probe Frequency Response	0.135	Tolerance	N	1.00	1	0.14	
Field Probe Linearity	0.013	Tolerance	N	1.00	1	0.01	
Modulation Interference Factor	0.20	Tolerance	R	1.73	1	0.12	Applicable for M-rating testing
Boundary Effects	0.105	Accuracy	R	1.73	1	0.06	*
Probe Positioning Accuracy	0.20	Accuracy	R	1.73	1	0.12	*
Probe Positioner	0.050	Accuracy	R	1.73	1	0.03	*
Extrapolation/Interpolation	0.045	Tolerance	R	1.73	1	0.03	*
Resolution to 2mm error	0.21	Tolerance	N	1.00	1	0.21	
System Detection Limit	0.05	Tolerance	R	1.73	1	0.03	*
Readout Electronics	0.015	Tolerance	N	1.00	1	0.02	*
Integration Time	0.11	Tolerance	R	1.73	1	0.06	*
Response Time	0.033	Tolerance	R	1.73	1	0.02	*
Phantom Thickness	0.10	Tolerance	R	1.73	1	0.06	*
System Repeatability (Field x 2=power)	0.17	Tolerance	N	1.00	1	0.17	*
Test Sample Related							
Device Positioning Vertical	0.2	Tolerance	R	1.73	1	0.12	*
Device Positioning Lateral	0.045	Tolerance	R	1.73	1	0.03	*
Device Holder and Phantom	0.1	Tolerance	R	1.73	1	0.06	*
Power Drift	0.21	Tolerance	R	1.73	1	0.12	
Combined Standard Uncertainty (k=1)						0.66	16.3%
Expanded Uncertainty [95% confidence]					1.31	32.6%	
Expanded Uncertainty [95% confidence]	on Field					0.66	16.3%

Notes:

- Test equipments are calibrated according to techniques outlined in NIS81, NIS3003 and NIST Tech Note 1297. All
 equipments have traceability according to NIST. Measurement Uncertainties are defined in further detail in NIS 81
 and NIST Tech Note 1297 and UKAS M3003.
- 2. * Uncertainty specifications from Schmidt & Partner Engineering AG (not site specific)

Measurement uncertainty reflects the quality and accuracy of a measured result as compared to the true value. Such statements are generally required when stating results of measurements so that it is clear to the intended audience that the results may differ when reproduced by different facilities. Measurement results vary due to the measurement uncertainty of the instrumentation, measurement technique, and test engineer. Most uncertainties are calculated using the tolerances of the instrumentation used in the measurement, the measurement setup variability, and the technique used in performing the test. While not generally included, the variability of the equipment under test also figures into the overall measurement uncertainty. Another component of the overall uncertainty is based on the variability of repeated measurements (so-called Type A uncertainty). This may mean that the Hearing Aid immunity tests may have to be repeated by taking down the test setup and resetting it up so that there are a statistically significant number of repeat measurements to identify the measurement uncertainty. By combining the repeat measurement results with that of the instrumentation chain using the technique contained in NIS 81 and NIS 3003, the overall measurement uncertainty was estimated.

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14. TEST DATA

See following Attached Pages for Test Data.

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DUT: CD835V3 - SN1003

Type: CD835V3 Serial: 1003

Communication System: CW; Frequency: 835 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 2/15/2021
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn1533; Calibrated: 12/8/2021
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (4);

835 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x361x1):

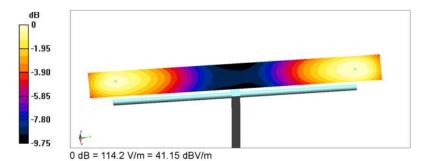
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 133.0 V/m; Power Drift = -0.15 dB

Applied MIF = 0.00 dB

Average Value of Peak (interpolated) = 112.7 V/m



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DUT: CD1880V3 - SN1137

Type: CD1880V3 Serial: 1137

Communication System: CW; Frequency: 1880 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 2/15/2021
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn1533; Calibrated: 12/8/2021
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (4);

1880 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

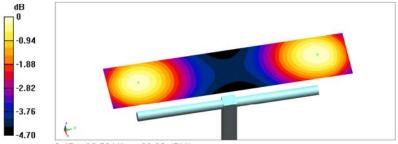
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 176.8 V/m; Power Drift = -0.09 dB

Applied MIF = 0.00 dB

Average Value of Peak (interpolated) = 92.1 V/m



0 dB = 92.52 V/m = 39.32 dBV/m

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Date: 1/4/2022



DUT: CD2600V3 - SN1012

Type: CD2600V3 Serial: 1012

Communication System: CW; Frequency: 2600 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 2/15/2021
- · Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn1533; Calibrated: 12/8/2021
- . Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (4);

2600 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

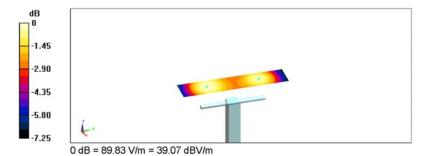
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 68.47 V/m; Power Drift = -0.01 dB

Applied MIF = 0.00 dB

Average Value of Peak (interpolated) = 88.4 V/m



FCC ID: A3LSMA135U

PCTEST
HAC (RF EMISSIONS) TEST REPORT

Quality Manager

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DUT: A3LSMA135U

Type: Portable Handset Serial: 20704 Backlight off Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 824.2 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 2/15/2021
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1533; Calibrated: 12/8/2021
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (4);

GSM850 Low Channel/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

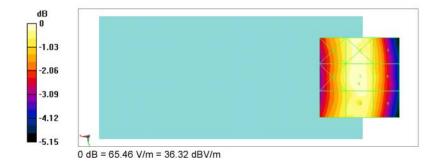
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 58.80 V/m; Power Drift = -0.17 dB

Applied MIF = 3.55 dB RF audio interference level = 36.37 dBV/m Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
35.72 dBV/m	36.3 dBV/m	35.43 dBV/m
		Grid 6 M4
35.76 dBV/m	36.37 dBV/m	35.58 dBV/m
		Grid 9 M4
35.64 dBV/m	36.26 dBV/m	35.45 dBV/m



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DUT: A3LSMA135U

Type: Portable Handset Serial: 20704 Backlight off Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 1909.8 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

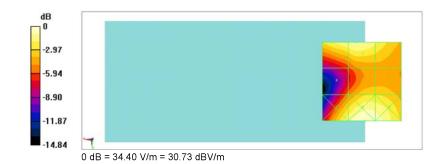
- Probe: EF3DV3 SN4035; Calibrated: 2/15/2021
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1533; Calibrated: 12/8/2021
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (4);

GSM1900 High Channel/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 16.36 V/m; Power Drift = -0.17 dB
Applied MIF = 3.54 dB
RF audio interference level = 30.08 dBV/m
Emission category: M3

MIF scaled E-field

Grid 1 M4	Grid 2 M3	Grid 3 M4
29.74 dBV/m	30.08 dBV/m	28.88 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
25.51 dBV/m	27.85 dBV/m	27.82 dBV/m
Grid 7 M4	Grid 8 M3	Grid 9 M3
29.46 dBV/m	30.77 dBV/m	30.38 dBV/m



FCC ID: A3LSMA135U	POTEST Proud to be part of & chemistr	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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DUT: A3LSMA135U

Type: Portable Handset Serial: 10952 Backlight off Duty Cycle: 1:4.67

Communication System: LTE TDD41; Frequency: 2549.5 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

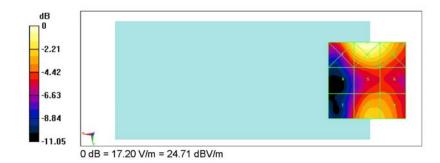
- Probe: EF3DV3 SN4035; Calibrated: 2/15/2021
- · Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1533; Calibrated: 12/8/2021
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (4);

Power Class 3 TDD LTE Band 41 Low Mid Channel, UL-DL 2, 15MHz BW, QPSK, 1RB, 0RB Offset **Hearing Aid Compatibility Test (101x101x1):**

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 10.18 V/m; Power Drift = -0.19 dB Applied MIF = 1.50 dB RF audio interference level = 22.37 dBV/m Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
23.64 dBV/m	24.71 dBV/m	23.78 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
19 dBV/m	20.68 dBV/m	20.54 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
20.14 dBV/m	22.37 dBV/m	22.07 dBV/m



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DUT: A3LSMA135U

Type: Portable Handset Serial: 10952 Backlight off Duty Cycle: 1:2.42

Communication System: LTE TDD41; Frequency: 2549.5 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

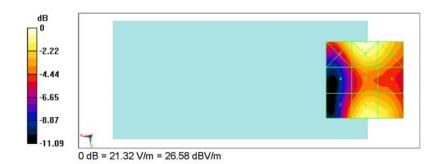
- Probe: EF3DV3 SN4035; Calibrated: 2/15/2021
- · Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1533; Calibrated: 12/8/2021
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (4);

Power Class 2 TDD LTE Band 41 Low Mid Channel, UL-DL 1, 15MHz BW, QPSK, 1RB, 0RB Offset **Hearing Aid Compatibility Test (101x101x1):**

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 20.22 V/m; Power Drift = -0.08 dB Applied MIF = -1.51 dB RF audio interference level = 25.76 dBV/m Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
25.5 dBV/m	26.58 dBV/m	25.79 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
21.62 dBV/m	23.58 dBV/m	23.21 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
23 64 dRV/m	25 76 dBV/m	25.32 dBV/m



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CALIBRATION CERTIFICATES 15.

The following pages include the probe calibration used to evaluate HAC for the DUT.

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PC Test Client

Certificate No: EF3_4035_Feb21

CALIBRATION CERTIFICATE

Object

EF3DV3- SN:4035

Calibration procedure(s)

QA CAL-02.v9, QA CAL-25.v7

Calibration procedure for E-field probes optimized for close near field

evaluations in air

Calibration date:

February 15, 2021

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate. 2/23/2021

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	01-Apr-20 (No. 217-03100/03101)	Apr-21
Power sensor NRP-Z91	SN: 103244	01-Apr-20 (No. 217-03100)	Apr-21
Power sensor NRP-Z91	SN: 103245	01-Apr-20 (No. 217-03101)	Apr-21
Reference 20 dB Attenuator	SN: CC2552 (20x)	31-Mar-20 (No. 217-03106)	Apr-21
DAE4_	SN: 789	23-Dec-20 (No. DAE4-789 Dec20)	Dec-21
Reference Probe ER3DV6	SN: 2328	05-Oct-20 (No. ER3-2328_Oct20)	Oct-21
Secondary Standards	ID	Check Date (in house)	Scheduled Check
Power meter E4419B	SN: GB41293874	06-Apr-16 (in house check Jun-20)	In house check: Jun-22
Power sensor E4412A	SN: MY41498087	06-Apr-16 (in house check Jun-20)	In house check: Jun-22
Power sensor E4412A	SN: 000110210	06-Apr-16 (in house check Jun-20)	In house check: Jun-22
RF generator HP 8648C	SN: US3642U01700	04-Aug-99 (in house check Jun-20)	In house check: Jun-22
Network Analyzer E8358A	SN: US41080477	31-Mar-14 (in house check Oct-20)	In house check: Oct-21

Michael Weber	Laboratory Technician	
	Caporatory recrimical	MINESET
Katja Pokovic	Technical Manager	III.
		Issued: February 16, 2021
		Katja Pokovic Technical Manager not be reproduced except in full without written approval of the laborator

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Glossary:

NORMx,y,z sensitivity in free space DCP diode compression point

CF crest factor (1/duty_cycle) of the RF signal A, B, C, D modulation dependent linearization parameters incident E-field orientation normal to probe axis En incident E-field orientation parallel to probe axis Εp

Polarization φ φ rotation around probe axis

Polarization 9 9 rotation around an axis that is in the plane normal to probe axis (at measurement center),

i.e., $\vartheta = 0$ is normal to probe axis

Connector Angle information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

a) IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005

b) CTIA Test Plan for Hearing Aid Compatibility, Rev 3.1.1, May 2017

Methods Applied and Interpretation of Parameters:

- *NORMx*, *y*, *z*: Assessed for E-field polarization ϑ = 0 for XY sensors and ϑ = 90 for Z sensor (f \leq 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- $NORM(f)x,y,z = NORMx,y,z * frequency_response$ (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z; Dx,y,z; VRx,y,z: A, B, C, D are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the NORMx (no uncertainty required).

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DASY/EASY - Parameters of Probe: EF3DV3 - SN:4035

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm $(\mu V/(V/m)^2)$	0.90	0.73	1.19	± 10.1 %
DCP (mV) ^B	96.3	101.2	98.2	

Calibration results for Frequency Response (30 MHz - 6 GHz)

Frequency MHz	Target E-Field V/m	Measured E-field (En) V/m	Deviation E-normal in %	Measured E-field (Ep) V/m	Deviation E-normal in %	Unc (k=2) %
30	77.1	77.0	-0.2%	77.2	0.1%	± 5.1 %
100	77.2	78.3	1.4%	77.8	0.7%	± 5.1 %
450	77.2	78.4	1.6%	77.9	1.0%	± 5.1 %
600	77.1	77.9	1.1%	77.4	0.5%	± 5.1 %
750	77.1	77.8	0.9%	77.3	0.3%	± 5.1 %
1800	143.1	139.0	-2.8%	139.4	-2.6%	± 5.1 %
2000	135.1	131.3	-2.7%	131.5	-2.6%	± 5.1 %
2200	127.7	123.4	-3.3%	124.5	-2.5%	± 5.1 %
2500	125.5	122.4	-2.5%	123.5	-1.6%	± 5.1 %
3000	79.4	75.6	-4.7%	76.7	-3.3%	± 5.1 %
3500	256.9	246.8	-3.9%	243.9	-4.8%	± 5.1 %
3700	251.2	240.8	-4.2%	237.9	-5.0%	± 5.1 %
5200	50.8	51.4	1.3%	51.7	1.9%	± 5.1 %
5500	47.0	46.8	-0.5%	48.2	2.7%	± 5.1 %
5800	48.8	48.6	-0.6%	47.1	-3.6%	± 5.1 %

Calibration Results for Modulation Response

UID	Communication System Name		A dB	B dB√μV	С	D dB	VR mV	Max dev.	Unc ^E (k=2)
0	CW	Х	0.0	0.0	1.0	0.00	141.8	± 3.8 %	± 4.7 %
		Υ	0.0	0.0	1.0	1	172.6		
		Z	0.0	0.0	1.0		171.7	_	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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Numerical linearization parameter: uncertainty not required.
Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

DASY/EASY - Parameters of Probe: EF3DV3 - SN:4035

Sensor Frequency Model Parameters

	Sensor X	Sensor Y	Sensor Z
Frequency Corr. (LF)	0.22	0.19	5.72
Frequency Corr. (HF)	2.82	2.82	2.82

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	-126.8
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	12 mm
Tip Length	25 mm
Tip Diameter	4 mm
Probe Tip to Sensor X Calibration Point	1.5 mm
Probe Tip to Sensor Y Calibration Point	1.5 mm
Probe Tip to Sensor Z Calibration Point	1.5 mm

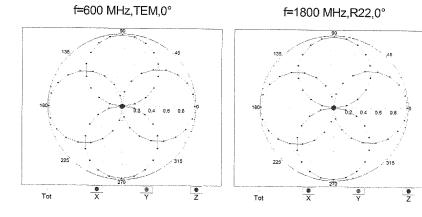
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EF3DV3 - SN:4035 February 15, 2021

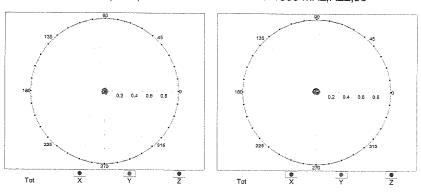
Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$



Receiving Pattern (ϕ), $\vartheta = 90^{\circ}$

f=600 MHz,TEM,90°

f=1800 MHz,R22,90°

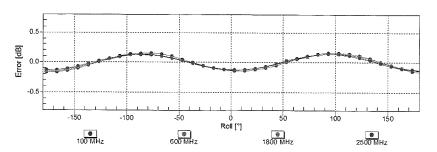


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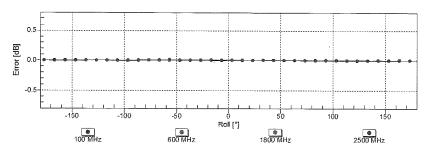
FCC ID: A3LSMA135U	PCTEST: Froud to be part of 6 seconds	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

Receiving Pattern (ϕ), $\vartheta = 90^{\circ}$



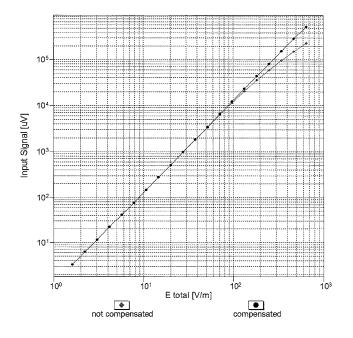
Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

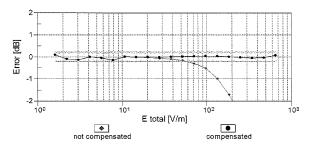
FCC ID: A3LSMA135U	PCTEST:	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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EF3DV3 - SN:4035 February 15, 2021

Dynamic Range f(E-field) (TEM cell, f = 900 MHz)



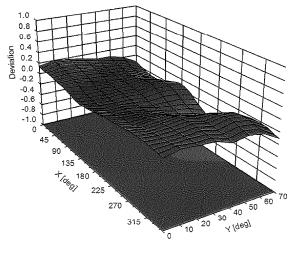


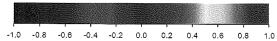
Uncertainty of Linearity Assessment: ± 0.6% (k=2)

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Deviation from Isotropy in Air Error (ϕ, ϑ) , f = 900 MHz





Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

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Client

PC Test

Accreditation No.: SCS 0108

Certificate No: CD835V3-1003 Jan21

CALIBRATION CERTIFICATE CD835V3 - SN: 1003 Object Calibration procedure(s) QA CAL-20.v7 Calibration Procedure for Validation Sources in air January 14, 2021 Calibration date: This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate. All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%, Calibration Equipment used (M&TE critical for calibration) **Primary Standards** Cal Date (Certificate No.) Scheduled Calibration Power meter NRP SN: 104778 01-Apr-20 (No. 217-03100/03101) Apr-21 Power sensor NRP-Z91 SN: 103244 01-Apr-20 (No. 217-03100) Apr-21 Power sensor NRP-Z91 SN: 103245 01-Apr-20 (No. 217-03101) Apr-21 Reference 20 dB Attenuator SN: BH9394 (20k) 31-Mar-20 (No. 217-03106) Apr-21 Type-N mismatch combination SN: 310982 / 06327 31-Mar-20 (No. 217-03104) Apr-21 Probe EF3DV3 SN: 4013 28-Dec-20 (No. EF3-4013_Dec20) Dec-21 DAE4 SN: 781 23-Dec-20 (No. DAE4-781_Dec20) Dec-21 Secondary Standards ID# Check Date (in house) Scheduled Check Power meter Agilent 4419B SN: GB42420191 09-Oct-09 (in house check Oct-20) In house check: Oct-23 Power sensor HP E4412A SN: US38485102 05-Jan-10 (in house check Oct-20) In house check: Oct-23 Power sensor HP 8482A SN: US37295597 09-Oct-09 (in house check Oct-20) In house check: Oct-23 RF generator R&S SMT-06 SN: 837633/005 10-Jan-19 (in house check Oct-20) In house check: Oct-23 Network Analyzer Agilent E8358A SN: US41080477 31-Mar-14 (in house check Oct-20) In house check: Oct-21 Name Function Signature Calibrated by: Leif Klysner Laboratory Technician Katia Pokovic Approved by: Technical Manager Issued: January 16, 2021 This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Certificate No: CD835V3-1003_Jan21

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References

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ANSI-C63.19-2011 American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 15 mm above the top metal edge of the dipole arms
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positionina: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic E-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any nonparallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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Approved by: PCTEST FCC ID: A3LSMA135U HAC (RF EMISSIONS) TEST REPORT SAMSUNG Quality Manager DUT Type: Filename: Test Dates: Page 50 of 71 1M2112270166-15-R3.A3L 1/4/2022 - 2/23/2022

Portable Handset

Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.10.4
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	835 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values at 835 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	109.9 V/m = 40.82 dBV/m
Maximum measured above low end	100 mW input power	106.8 V/m = 40.57 dBV/m
Averaged maximum above arm	100 mW input power	108.4 V/m ± 12.8 % (k=2)

Appendix (Additional assessments outside the scope of SCS 0108)

Antenna Parameters

Frequency	Return Loss	Impedance	
800 MHz	17.0 dB	40.3 Ω - 8.2 jΩ	
835 MHz	24.5 dB	52.9 Ω + 5.4 jΩ	
880 MHz	17.2 dB	61.3 Ω - 10.6 jΩ	
900 MHz	18.6 dB	50.5 Ω - 11.9 jΩ	
945 MHz	21.9 dB	51.3 Ω + 8.0 jΩ	

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

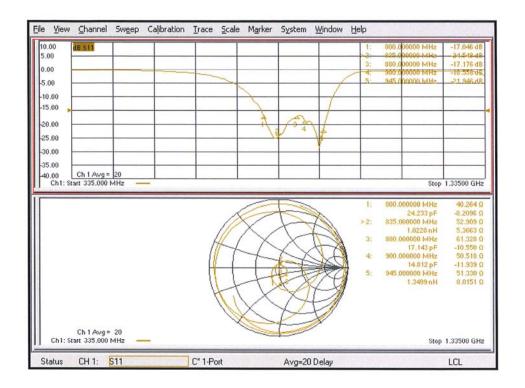
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

Certificate No: CD835V3-1003_Jan21 Page 3 of 5

FCC ID: A3LSMA135U	PCTEST*	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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Impedance Measurement Plot



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FCC ID: A3LSMA135U	PCTEST Proud to be part of & elements	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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DASY5 E-field Result

Date: 14.01.2021

Test Laboratory: SPEAG Lab2

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1003

Communication System: UID 0 - CW ; Frequency: 835 MHz Medium parameters used: $\sigma=0$ S/m, $\epsilon_r=1$; $\rho=0$ kg/m³ Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 835 MHz; Calibrated: 28.12.2020
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 23.12.2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.4(1527); SEMCAD X 14.6.14(7483)

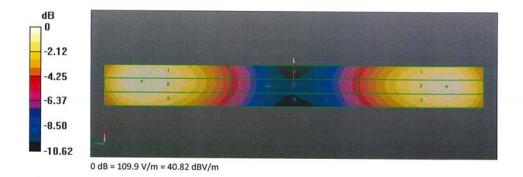
Dipole E-Field measurement @ 835MHz/E-Scan - 835MHz d=15mm/Hearing Aid Compatibility Test (41x361x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 132.2 V/m; Power Drift = 0.03 dB
Applied MIF = 0.00 dB
RF audio interference level = 40.82 dBV/m

Emission category: M3

MIF scaled E-field

Grid 1 M3	Grid 2 M3	Grid 3 M3
40.45 dBV/m	40.57 dBV/m	40.35 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
35.95 dBV/m	35.96 dBV/m	35.61 dBV/m
Grid 7 M3	Grid 8 M3	Grid 9 M3
40.79 dBV/m	40.82 dBV/m	40.4 dBV/m



Certificate No: CD835V3-1003_Jan21

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FCC ID: A3LSMA135U	PCTEST	HAC (RE EMISSIONS) TEST REPORT		Approved by: Quality Manager
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Schweizerischer Kalibrierdienst Service suisse d'étalonnage С Servizio svizzero di taratura S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS) The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 0108

Certificate No: CD1880V3-1137_Jan21

CALIBRATION CERTIFICATE CD1880V3 - SN: 1137 Object QA CAL-20.v7 Calibration procedure(s) Calibration Procedure for Validation Sources in air Calibration date: January 14, 2021 This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate. All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%. Calibration Equipment used (M&TE critical for calibration) Primary Standards ID# Cal Date (Certificate No.) Scheduled Calibration Power meter NRP SN: 104778 01-Apr-20 (No. 217-03100/03101) Apr-21 Power sensor NRP-Z91 SN: 103244 01-Apr-20 (No. 217-03100) Apr-21 Power sensor NRP-Z91 SN: 103245 01-Apr-20 (No. 217-03101) Apr-21 Reference 20 dB Attenuator SN: BH9394 (20k) 31-Mar-20 (No. 217-03106) Apr-21 Type-N mismatch combination SN: 310982 / 06327 31-Mar-20 (No. 217-03104) Apr-21 Probe EF3DV3 SN: 4013 28-Dec-20 (No. EF3-4013_Dec20) Dec-21 DAE4 SN: 781 23-Dec-20 (No. DAE4-781_Dec20) Dec-21 Secondary Standards ID# Check Date (in house) Scheduled Check Power meter Agilent 4419B SN: GB42420191 09-Oct-09 (in house check Oct-20) In house check: Oct-23 Power sensor HP E4412A SN: US38485102 05-Jan-10 (in house check Oct-20) In house check: Oct-23 SN: US37295597 Power sensor HP 8482A 09-Oct-09 (in house check Oct-20) In house check: Oct-23 RF generator R&S SMT-06 SN: 837633/005 10-Jan-19 (in house check Oct-20) In house check: Oct-23 Network Analyzer Agilent E8358A SN: US41080477 31-Mar-14 (in house check Oct-20) In house check: Oct-21 Function Calibrated by: Leif Klysner Laboratory Technician Katia Pokovic Approved by: Technical Manager Issued: January 16, 2021 This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Certificate No: CD1880V3-1137_Jan21

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FCC ID: A3LSMA135U	PCTEST HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
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Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

References

[1] ANSI-C63.19-2011

American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
 (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes.
 In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
 distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
 figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
 is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
 directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a Vector Network Analyzer.
 The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic E-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

Certificate No: CD1880V3-1137 Jan21 Page 2 of 7

FCC ID: A3LSMA135U

Approved by:

HAC (RF EMISSIONS) TEST REPORT

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 1M2112270166-15-R3.A3L
 1/4/2022 - 2/23/2022
 Portable Handset

Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.10.4
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	1730 MHz ± 1 MHz 1880 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values at 1730 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum	
Maximum measured above high end	100 mW input power	94.2 V/m = 39.48 dBV/m	
Maximum measured above low end	100 mW input power	93.8 V/m = 39.44 dBV/m	
Averaged maximum above arm	100 mW input power	94.0 V/m ± 12.8 % (k=2)	

Maximum Field values at 1880 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum	
Maximum measured above high end	100 mW input power	88.0 V/m = 38.89 dBV/m	
Maximum measured above low end	100 mW input power	87.8 V/m = 38.87 dBV/m	
Averaged maximum above arm	100 mW input power	87.9 V/m ± 12.8 % (k=2)	

Certificate No: CD1880V3-1137_Jan21

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FCC ID: A3LSMA135U	PCTEST Proud to be part of & common	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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Appendix (Additional assessments outside the scope of SCS 0108)

Antenna Parameters

Nominal Frequencies

Frequency	Return Loss	Impedance	
1730 MHz	22.8 dB	54.0 Ω + 6.4 jΩ	
1880 MHz	21.4 dB	56.8 Ω + 6.0 jΩ	
1900 MHz	22.7 dB	57.2 Ω + 3.0 jΩ	
1950 MHz	27.9 dB	52.3 Ω - 3.4 jΩ	
2000 MHz	· 20.4 dB	42.8 Ω + 5.2 jΩ	

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

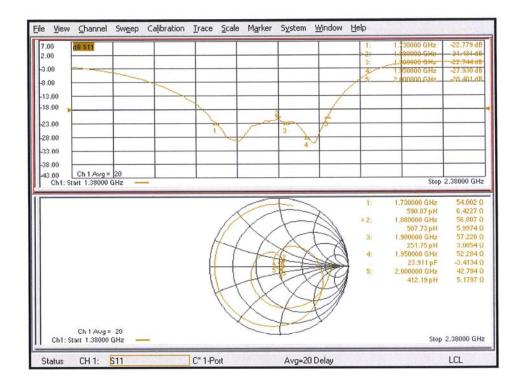
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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FCC ID: A3LSMA135U	POTEST Pour to be post or second	HAC (RE EMISSIONS) TEST REPORT		Approved by: Quality Manager
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Impedance Measurement Plot



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DASY5 E-field Result

Date: 14.01.2021

Test Laboratory: SPEAG Lab2

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: CD1880V3 - SN: 1137

Communication System: UID 0 - CW ; Frequency: 1880 MHz, Frequency: 1730 MHz

Medium parameters used: $\sigma = 0$ S/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 1880 MHz, ConvF(1, 1, 1) @ 1730 MHz; Calibrated: 28.12.2020
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 23.12.2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.4(1527); SEMCAD X 14.6.14(7483)

Dipole E-Field measurement @ 1880MHz/E-Scan - 1880MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 157.0 V/m; Power Drift = 0.02 dB

Applied MIF = 0.00 dB

RF audio interference level = 38.89 dBV/m

Emission category: M2

MIF scaled E-field

Grid 1 M2	Grid 2 M2	Grid 3 M2
38.7 dBV/m	38.87 dBV/m	38.68 dBV/m
Grid 4 M2	Grid 5 M2	Grid 6 M2
36.04 dBV/m	36.09 dBV/m	35.98 dBV/m
Grid 7 M2	Grid 8 M2	Grid 9 M2
38.81 dBV/m	38.89 dBV/m	38.56 dBV/m

Certificate No: CD1880V3-1137_Jan21

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FCC ID: A3LSMA135U	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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Dipole E-Field measurement @ 1880MHz/E-Scan - 1730MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 169.8 V/m; Power Drift = 0.01 dB

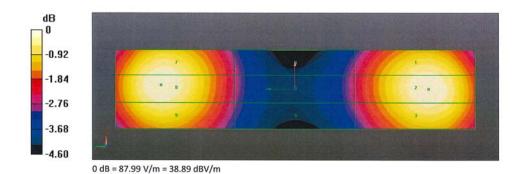
Applied MIF = 0.00 dB

RF audio interference level = 39.48 dBV/m

Emission category: M2

MIF scaled E-field

	Grid 2 M2 39.44 dBV/m	Grid 3 M2 39.24 dBV/m
The state of the s	Grid 5 M2 36.74 dBV/m	Grid 6 M2 36.58 dBV/m
	Grid 8 M2 39.48 dBV/m	Grid 9 M2 39.13 dBV/m



Certificate No: CD1880V3-1137_Jan21

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FCC ID: A3LSMA135U	PCTEST:	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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Calibration Laboratory of Schmid & Partner **Engineering AG**

Zeughausstrasse 43, 8004 Zurich, Switzerland





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Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

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Client

PC Test

Certificate No: CD2600V3-1012 Jan21 **CALIBRATION CERTIFICATE** CD2600V3 - SN: 1012 Object QA CAL-20.v7 Calibration procedure(s) Calibration Procedure for Validation Sources in air January 14, 2021 Calibration date: This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate. All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%. 3/30/2021 Calibration Equipment used (M&TE critical for calibration) Primary Standards ID# Cal Date (Certificate No.) Scheduled Calibration Power meter NRP SN: 104778 01-Apr-20 (No. 217-03100/03101) Apr-21 Power sensor NRP-Z91 SN: 103244 01-Apr-20 (No. 217-03100) Apr-21 SN: 103245 Power sensor NRP-Z91 01-Apr-20 (No. 217-03101) Apr-21 SN: BH9394 (20k) Reference 20 dB Attenuator 31-Mar-20 (No. 217-03106) Apr-21 Type-N mismatch combination SN: 310982 / 06327 31-Mar-20 (No. 217-03104) Apr-21 Probe EF3DV3 SN: 4013 28-Dec-20 (No. EF3-4013_Dec20) Dec-21 DAE4 SN: 781 23-Dec-20 (No. DAE4-781_Dec20) Dec-21 Secondary Standards ID# Check Date (in house) Scheduled Check SN: GB42420191 Power meter Agilent 4419B 09-Oct-09 (in house check Oct-20) In house check: Oct-23 Power sensor HP E4412A In house check: Oct-23 SN: US38485102 05-Jan-10 (in house check Oct-20) SN: US37295597 Power sensor HP 8482A 09-Oct-09 (in house check Oct-20) In house check: Oct-23 RF generator R&S SMT-06 SN: 837633/005 10-Jan-19 (in house check Oct-20) In house check: Oct-23 Network Analyzer Agilent E8358A SN: US41080477 31-Mar-14 (in house check Oct-20) In house check: Oct-21 Name Function Signature Calibrated by: Leif Klysner Laboratory Technician Approved by: Katja Pokovic Technical Manager Issued: January 16, 2021 This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Certificate No: CD2600V3-1012_Jan21

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FCC ID: A3LSMA135U	PCTEST Proud to be port of Sements	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

References

ANSI-C63.19-2011
 American National Standard, Methods of Measurement of Compatibility between Wireless Communications
 Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
 (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes.
 In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
 distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
 figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
 is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
 directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a Vector Network Analyzer.
 The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic E-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

Certificate No: CD2600V3-1012 Jan21

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FCC ID: A3LSMA135U	PCTEST*	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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Measurement Conditions

DASY system configuration, as far as not given on page 1

DASY Version	DASY5	V52.10.4
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	2600 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values at 2600 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum	
Maximum measured above high end	100 mW input power	86.8 V/m = 38.77 dBV/m	
Maximum measured above low end	100 mW input power	86.3 V/m = 38.72 dBV/m	
Averaged maximum above arm	100 mW input power	86.5 V/m ± 12.8 % (k=2)	

Appendix (Additional assessments outside the scope of SCS 0108)

Antenna Parameters

Frequency	Return Loss	Impedance	
2450 MHz	20.9 dB	43.7 Ω - 5.7 jΩ	
2550 MHz	32.2 dB	48.5 Ω + 1.9 jΩ	
2600 MHz	35.0 dB	51.4 Ω + 1.1 jΩ	
2650 MHz	31.6 dB	52.4 Ω - 1.2 jΩ	
2750 MHz	22.3 dB	48.4 Ω - 7.4 jΩ	

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

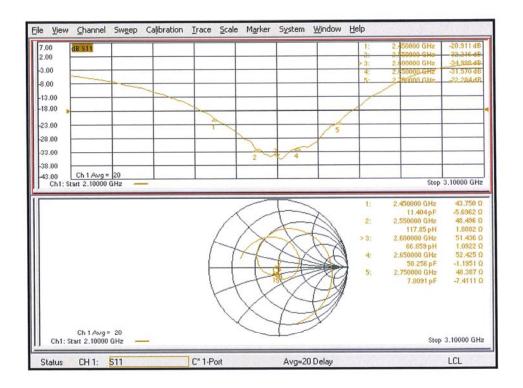
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

Certificate No: CD2600V3-1012_Jan21 Page 3 of 5

FCC ID: A3LSMA135U	PCTEST Proud to be part of Sements	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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Impedance Measurement Plot



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FCC ID: A3LSMA135U	PCTEST Proud to be part of & elements	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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1M2112270166-15-R3.A3L	1/4/2022 - 2/23/2022	Portable Handset		Page 64 of 71

DASY5 E-field Result

Date: 14.01.2021

Test Laboratory: SPEAG Lab2

DUT: HAC Dipole 2600 MHz; Type: CD2600V3; Serial: CD2600V3 - SN: 1012

Communication System: UID 0 - CW ; Frequency: 2600 MHz Medium parameters used: $\sigma=0$ S/m, $\epsilon_r=1$; $\rho=0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 2600 MHz; Calibrated: 28.12.2020
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 23.12.2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.4(1527); SEMCAD X 14.6.14(7483)

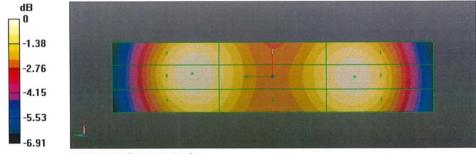
Dipole E-Field measurement @ 2600MHz/E-Scan - 2600MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 67.09 V/m; Power Drift = -0.03 dB Applied MIF = 0.00 dB RF audio interference level = 38.77 dBV/m Emission category: M2

501 3. 11.2

MIF scaled E-field

Grid 1 M2	Grid 2 M2	Grid 3 M2
38.56 dBV/m	38.72 dBV/m	38.5 dBV/m
Grid 4 M2	Grid 5 M2	Grid 6 M2
38.08 dBV/m	38.12 dBV/m	37.92 dBV/m
Grid 7 M2	Grid 8 M2	Grid 9 M2
38.69 dBV/m	38.77 dBV/m	38.5 dBV/m



0 dB = 86.78 V/m = 38.77 dBV/m

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16. CONCLUSION

The measurements indicate that the referenced wireless communications device complies with the HAC limits specified in accordance with the ANSI C63.19 Standard and FCC WT Docket No. 01-309 RM-8658. Precise laboratory measures were taken to assure repeatability of the tests. The tested device complies with the requirements in respect to all parameters specific to the test. The test results and statements relate only to the item(s) tested.

Please note that the M-rating for this equipment only represents the field interference possible against a hypothetical and typical hearing aid. The measurement system and techniques presented in this evaluation are proposed in the ANSI standard as a means of best approximating wireless device compatibility with a hearing-aid. The literature is under continual re-construction.

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